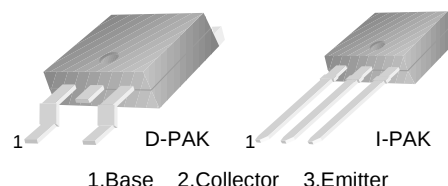


KSH210

KSH210

D-PAK for Surface Mount Applications

- High DC Current Gain
- Low Collector Emitter Saturation Voltage
- Lead Formed for Surface Mount Applications (No Suffix)
- Straight Lead (I-PAK, " - I " Suffix)



PNP Epitaxial Silicon Transistor

Absolute Maximum Ratings $T_C=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage	- 40	V
V_{CEO}	Collector-Emitter Voltage	- 25	V
V_{EBO}	Emitter-Base Voltage	- 8	V
I_C	Collector Current (DC)	- 5	A
I_{CP}	Collector Peak Current (Pulse)	- 10	A
I_B	Base Current	- 1	A
P_C	Collector Dissipation ($T_C = 25^\circ\text{C}$)	12.5	W
	Collector Dissipation ($T_a = 25^\circ\text{C}$)	1.4	W
T_J	Junction Temperature	150	$^\circ\text{C}$
T_{STG}	Storage Temperature	- 65 ~ 150	$^\circ\text{C}$

Electrical Characteristics $T_C=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
$V_{CEO(sus)}$	* Collector-Emitter Sustaining Voltage	$I_C = - 10\text{mA}$, $I_B = 0$	-25		V
I_{CBO}	Collector Cut-off Current	$V_{CB} = - 40\text{V}$, $I_E = 0$		-100	nA
I_{EBO}	Emitter Cut-off Current	$V_{EB} = - 8\text{V}$, $I_C = 0$		-100	nA
h_{FE}	* DC Current Gain	$V_{CE} = - 1\text{V}$, $I_C = - 500\text{mA}$ $V_{CE} = - 1\text{V}$, $I_C = - 2\text{A}$ $V_{CE} = - 2\text{V}$, $I_C = - 5\text{A}$	70 45 10	180	
$V_{CE(sat)}$	* Collector-Emitter Saturation Voltage	$I_C = - 500\text{mA}$, $I_B = - 50\text{mA}$ $I_C = - 2\text{A}$, $I_B = - 200\text{mA}$ $I_C = - 5\text{A}$, $I_B = - 1\text{A}$		-0.3 -0.75 -1.8	V V V
$V_{BE(sat)}$	* Base-Emitter Saturation Voltage	$I_C = - 5\text{A}$, $I_B = - 1\text{A}$		-2.5	V
$V_{BE(on)}$	* Base-Emitter On Voltage	$V_{CE} = - 1\text{V}$, $I_C = - 2\text{A}$		-1.6	V
f_T	Current Gain Bandwidth Product	$V_{CE} = - 10\text{V}$, $I_C = - 100\text{mA}$	65		MHz
C_{ob}	Output Capacitance	$V_{CB} = - 10\text{V}$, $I_E = 0$, $f = 0.1\text{MHz}$		120	pF

* Pulse Test: $PW \leq 300\mu\text{s}$, Duty Cycle $\leq 2\%$

Typical Characteristics

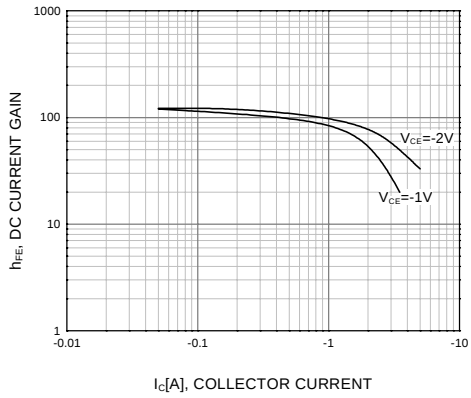


Figure 1. DC current Gain

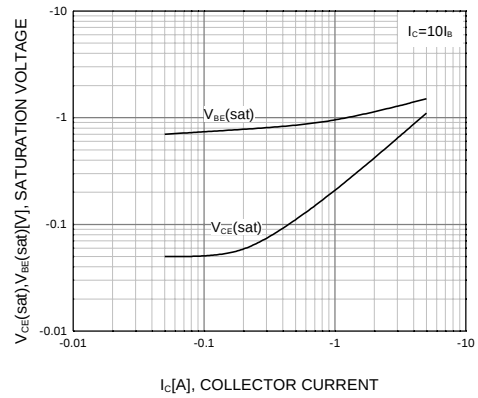


Figure 2. Base-Emitter Saturation Voltage
Collector-Emitter Saturation Voltage

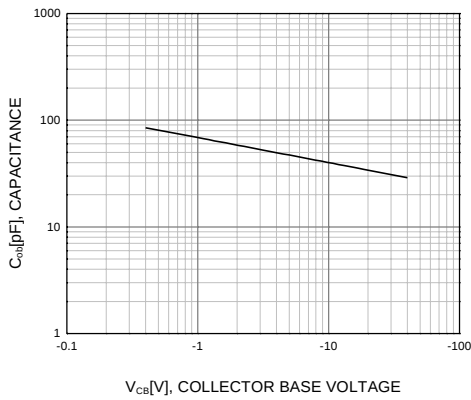


Figure 3. Collector Output Capacitance

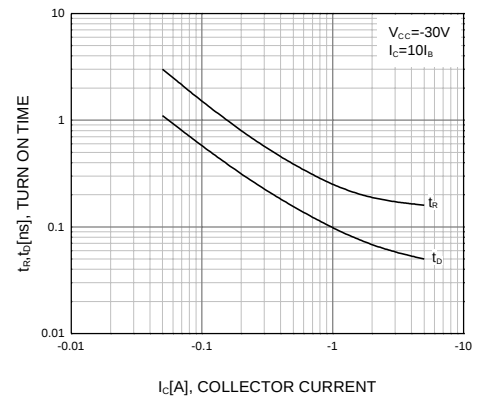


Figure 4. Turn On Time

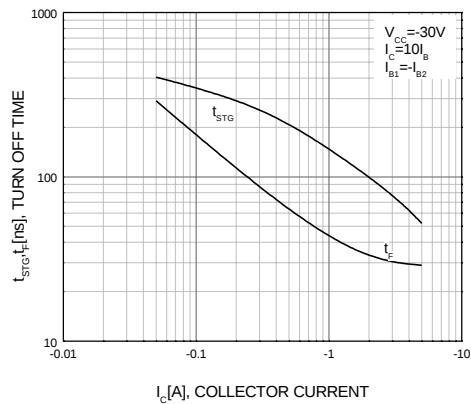


Figure 5. Turn Off Time

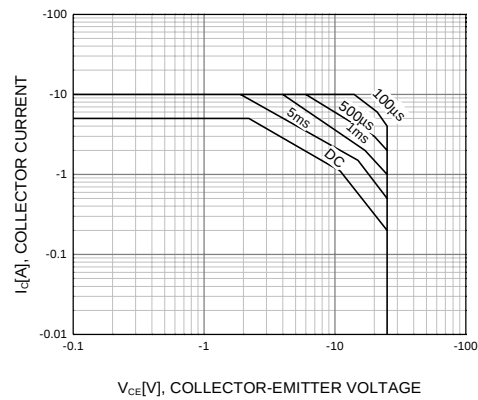


Figure 6. Safe Operating Area

Typical Characteristics (Continued)

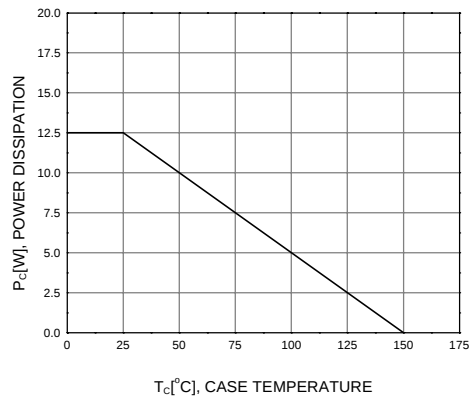
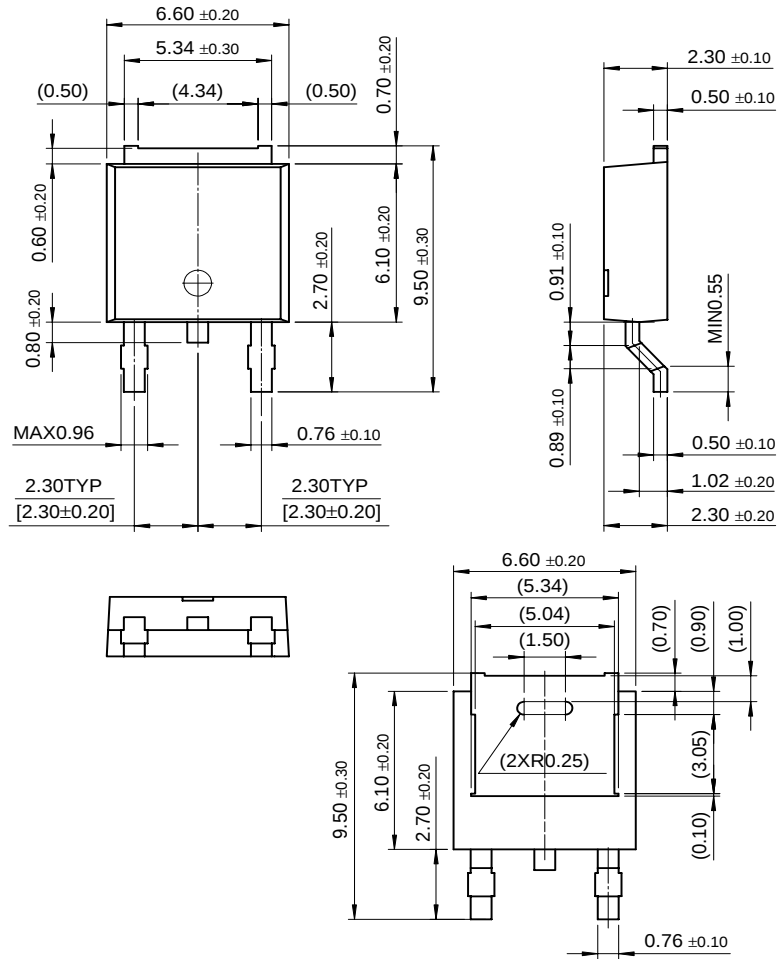


Figure 7. Power Derating

Package Dimensions

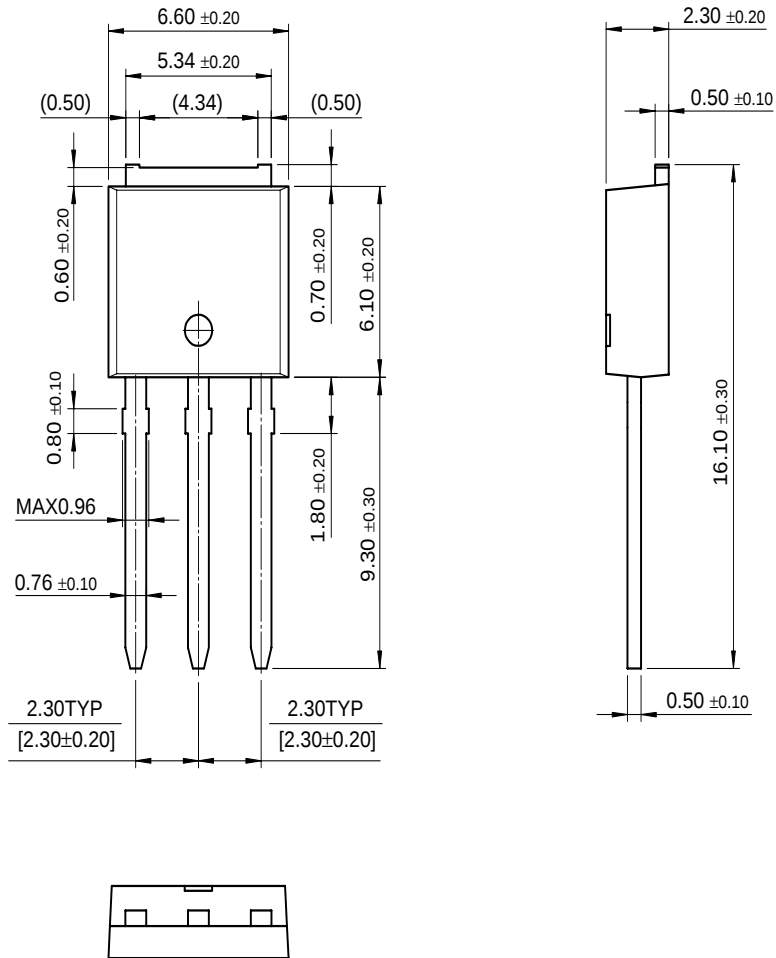
D-PAK



Dimensions in Millimeters

Package Dimensions (Continued)

I-PAK



Dimensions in Millimeters

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